

# Silicon Diode

## **1N4002**

100V/1A

# DATASHEET

OEM – Fairchild

Source: Fairchild Databook 1978

# 1N4001 • 1N4007

## 1 A SILICON RECTIFIERS

- GLASS PACKAGE
- 1000 V RATING (1N4007)

### ABSOLUTE MAXIMUM RATINGS (Note 1)

#### Temperatures

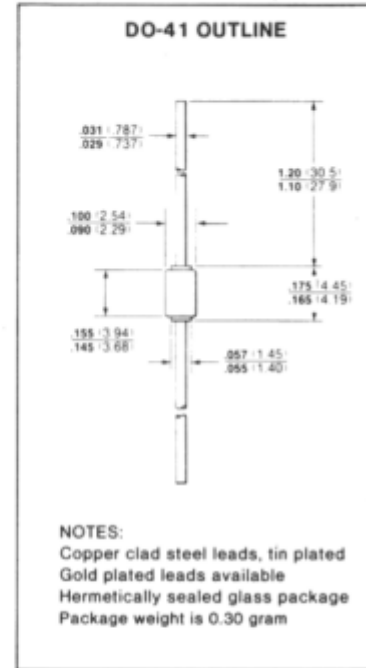
Storage Temperature Range	-65°C to +175°C
Maximum Junction Operating Temperature	+175°C
Lead Temperature	+260°C

#### Maximum Voltages and Currents

VRRM	Peak Repetitive Reverse Voltage	1N4001	50 V
VRWM	Working Peak Reverse Voltage	1N4002	100 V
VR	DC Blocking Voltage	1N4003	200 V
		1N4004	400 V
		1N4005	600 V
		1N4006	800 V
		1N4007	1000 V

		1N4001	35 V
		1N4002	70 V
		1N4003	140 V
VR(rms)	rms Reverse Voltage	1N4004	280 V
		1N4005	420 V
		1N4006	560 V
		1N4007	700 V

IO	Average Rectified Forward Current (Note 2)	1 A
IFSM	Peak Forward Surge Current	30 A



### ELECTRICAL CHARACTERISTICS (25°C Ambient Temperature unless otherwise noted)

SYMBOL	CHARACTERISTIC	TYP	MAX	UNITS	TEST CONDITIONS
V <sub>F</sub>	Forward Voltage	0.95	1.10	V	I <sub>O</sub> = 1.0 A, T <sub>A</sub> = 75°C
V <sub>F(AV)</sub>	Average Forward Voltage	0.75	0.80	V	I <sub>F</sub> = 1 A
V <sub>FM</sub>	Peak Forward Voltage	1.40	1.60	V	I <sub>O</sub> = 1.0 A
I <sub>R</sub>	Reverse Current	0.05 0.5	10.0 50	μA	Rated dc Voltage Rated dc Voltage, T <sub>A</sub> = 100°C
I <sub>R(AV)</sub>	Average Reverse Current	1.0	30	μA	Rated V <sub>R</sub> , I <sub>O</sub> = 1.0 A
t <sub>rr</sub>	Reverse Recovery Time (Note 3)	1.0		μs	I <sub>F</sub> = 1.0 A, V <sub>r</sub> = 30 V

#### NOTES:

- These are limiting values above which the serviceability of the rectifier may be impaired.
- Derate Linearly above T<sub>A</sub> = 75°C (Note 3).
- For product family characteristic curves and test circuit, refer to Chapter 4, D16.

**CURVE SET NUMBER D16**  
**GENERAL PURPOSE 1 A RECTIFIER**

